

# 2X4.5W Class-G Stereo Audio Power Amplifier with Automatic Level Control & Battery Tracking AGC

#### GENERAL DESCRIPTION

The ft2923 is a highly efficient 2X4.5W Class-G stereo audio power amplifier with automatic level control (ALC) and battery tracking AGC. It integrates dual filterless Class-D audio amplifiers with an adaptive Class-G synchronous boost regulator and operates with a range of supply voltages from 3V to 5.5V. When operating with 3.6V supply voltage, the ft2923 can deliver an output power of 4.5W per channel with 10% THD+N, or an ALC output power of 3.5W per channel with 0.3% THD+N, into a pair of  $4\Omega$  speakers.

In ft2923, the power supply rails of the audio amplifiers' output stages are internally boosted and regulated by a synchronous PWM switching regulator with two integrated power switches. The boost regulator employs current-mode PWM control with proprietary Class-G operation to regulate the boosted output voltage dynamically in response to the voltage level of the audio outputs.

The ft2923 features ALC function to constantly monitor and safeguard the audio outputs against the boosted supply voltages, preventing output clipping distortion, excessive power dissipation, and speaker over-load. Once an over-level condition is detected in either channel, the ALC lowers the voltage gain of both audio amplifiers together to limit the peak audio outputs.

In conjunction with ALC, as the battery supply voltage drops below a prescribed value, the battery tracking AGC lowers the voltage gain of both audio amplifiers to limit the peak audio outputs, preventing the collapse of battery voltage.

#### **FEATURES**

- Wide range of supply voltages from 3V to 5.5V
- Filterless Class-D audio amplifier integrated with a Class-G synchronous boost regulator
- Automatic level control to eliminate output clipping
- Battery tracking AGC to prevent battery collapse
- Soft drive mode for EMI reduction
- Maximum output power (Non-ALC Mode) (VBAT=3.6V, ALC=VBAT, THD+N=10%)
  - 4.5W/Ch (4Ω Load)
  - 2.7W/Ch (8Ω Load)
- ALC output power (ALC Mode) (VBAT=3.6V, ALC=NC, THD+N=0.3%)
  - 3.5W/Ch (4Ω Load)
  - 2.0W/Ch (8Ω Load)
- Wide ALC dynamic range: 13dB
- Maximum voltage gain: 30dB
- High efficiency: 76%
  (VBAT=3.6V, 4Ω Load, Po=2W/Ch, both channels driven)
- Volume fade-in and fade-out
- Under-voltage lockout protection
- Auto-recovering over-current & short-circuit protection
- Thermal over-load protection
- Available in TSSOP-28L package

#### **APPLICATIONS**

- Blue Tooth Speakers
- Portable Audio Decks
- Consumer Audio Electronics

#### **APPLICATION CIRCUIT**

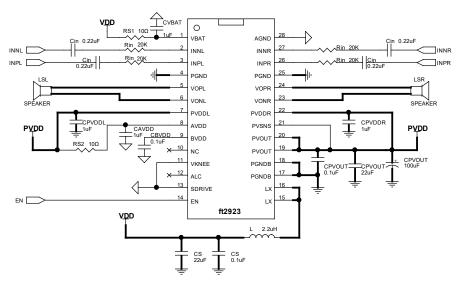
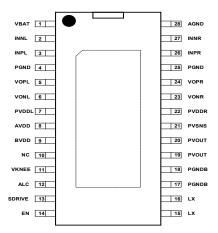


Figure 1: Typical Application Circuit of ft2923



#### PIN CONFIGURATION AND DESCRIPTION



ft2923P (TOP VIEW)

NAME	PIN#	TYPE	DESCRIPTION
VBAT	1	Р	Supply input voltage. Connect to a $1\mu F$ capacitor for decoupling. It is externally connected to the system supply through a small decoupling resistor of $10\Omega$ .
INNL	2	Al	Left-channel inverting audio input terminal.
INPL	3	Al	Left-channel non-inverting audio input terminal.
PGND	4	G	Power ground for the left-channel audio amplifier's output stage.
VOPL	5	AO	Left-channel non-inverting audio output terminal.
VONL	6	AO	Left-channel inverting audio output terminal.
PVDDL	7	Р	Power supply input for the left-channel audio amplifier's output stage. Connect directly to the output capacitor of PVOUT. Also, connect to a 1µF capacitor for decoupling.
AVDD	8	Р	Boosted supply input voltage for internal circuitry. Connect it to a $1\mu F$ capacitor for decoupling. Also, place a small decoupling resistor of $10\Omega$ between this pin and PVOUT.
BVDD	9	AO	Internally generated voltage reference. Connect to a 0.1µF capacitor for decoupling.
VKNEE	11	DI	<b>Battery Tracking AGC Control</b> with an internal $300$ kΩ pullup resistor to VBAT and an internal $300$ kΩ pulldown resistor to ground.
ALC	12	DI	<b>ALC Mode Control</b> with an internal $300$ k $\Omega$ pullup resistor to VBAT and an internal $300$ k $\Omega$ pulldown resistor to ground.
SDRIVE	13	DI	<b>Soft Drive Mode Control</b> with an internal $300k\Omega$ pullup resistor to VBAT and an internal $300k\Omega$ pulldown resistor to ground. When unconnected, the boost regulator is disabled.
EN	14	DI	Chip Enable (Active High) with an internal 300kΩ pulldown resistor to ground.
LX	15, 16	AO	Switch node of the boost regulator.
PGNDB	17, 18	G	Power ground for the boost regulator's output stage.
PVOUT	19, 20	Р	Boosted voltage output.
PVSNS	21	Al	Boosted voltage sense. Connect directly to the output capacitor of PVOUT.
PVDDR	22	Р	Power supply input for the right-channel audio amplifier's output stage. Connect directly to the output capacitor of PVOUT. Also, connect to a 1µF capacitor for decoupling.
VONR	23	AO	Right-channel inverting audio output terminal.
VOPR	24	AO	Right-channel non-inverting audio output terminal.
PGND	25	G	Power ground for the right-channel audio amplifier's output stage.
INPR	26	Al	Right-channel non-inverting audio input terminal.
INNR	27	Al	Right-channel inverting audio input terminal.
AGND	28	G	Analog ground.
NC	10		No internal connection.

#### **ORDERING INFORMATION**

PART NUMBER	TEMPERATURE RANGE	PACKING OPTION	PACKAGE
ft2923P	-40°C to +85°C	Tape and Reel, 4000	TSSOP-28L



## ABSOLUTE MAXIMUM RATINGS (Note1)

PARAMETER	VALUE
Supply Voltage, VBAT	-0.3V to 6V
LX, PVOUT, PVDDL/R, PVSNS, AVDD, VOPL/R, VONL/R	-0.3V to 7.5V
PGND, PGNDB	-0.3V to 0.3V
All other Pins	-0.3V to VBAT+0.3V
Operating Junction Temperature	-40°C to +150°C
Storage Temperature	-40°C to +125°C
ESD Ratings-Human Body Model (HBM)	4000V
Maximum Soldering Temperature (@10 second duration)	260°C

Note 1: Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at any conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may also affect device reliability.

## **POWER DISSIPATION RATINGS** (Note 2, 3)

PACKAGE	T <sub>A</sub> <u>&lt;</u> +25°C	T <sub>A</sub> = +70°C	T <sub>A</sub> = +85°C	$\Theta_{JA}$
TSSOP-28L	4.5W	2.8W	2.3W	28°C/W

Note 2: The thermal pad of the package must be directly soldered onto a grounded metal island as a thermal sink on the system board.

Note 3: The power dissipation ratings are for a two-side, two-plane printed circuit board (PCB).

#### RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Supply Voltage	$V_{DD}$	@ VBAT	3.0		5.5	V
Operating Ambient Temperature	T <sub>A</sub>		-40		85	°C
Minimum Load Impedance	$R_L$	Across VOPL/R & VONL/R	3.2	4		Ω
Audio Input Resistor	R <sub>IN</sub>	@ INPL/R, INNL/R	0		56	kΩ
Audio Input Capacitor	C <sub>IN</sub>	@ INPL/R, INNL/R	0.1	0.22	1.0	μF
Boost Regulator Inductor	L		1.5	2.2	3.3	μΗ
Boost Regulator Input Capacitor	C <sub>S</sub>	Ceramic	10	22		μF
Baset Baselleton Outset Compaiton		Ceramic	22	44		μF
Boost Regulator Output Capacitor	C <sub>PVOUT</sub>	Electrolytic or Tantalum (Note 4)	47	100		μF
BVDD Output Capacitor	C <sub>BVDD</sub>			0.1		μF
PVDD Decoupling Capacitors	C <sub>PVDDL/R</sub>			1		μF
		High η Drive, Boost regulator Enabled Short to GND				
Operating Mode Control	SDRIVE	Soft Drive, Boost regulator Disabled		Unconnected		
		Soft Drive, Boost regulator Enabled	Short to VBAT			
		ALC-1		Short to GND		
ALC Mode Control	ALC	ALC-2	Unconnected			
		Non-ALC	Short to VBAT			
		Battery Tracking AGC Disabled	Short to GND			
Battery Tracking AGC Control	VKNEE	VKNEE=3.15V	Unconnected			
		VKNEE=3.40V	Short to VBAT			

Note 4: A bulk output capacitor (either electrolytic or tantalum) is typically added to facilitate higher voltage margin for higher audio power at low frequencies. However, be cautious using any bulk output capacitance higher than 100µF as it might adversely slow the boost regulator's response to load transients to some extent affecting audio dynamics when playing music.



#### **IMPORTANT APPLICATION NOTES**

- 1. It is crucial to place the ft2923 in close proximity to the inductor, Schottky diode (if present), and input/output capacitors of the boost regulator on the system board, minimizing parasitic resistances and inductances of high-current traces. Also, these passive components must be placed on the same layer with ft2923 and connected with wide and short metal lines without vias. Failure to do a proper layout on the system board can result in significant degradation of maximum output power, efficiency, THD, and EMI performance. It might even induce excessive ringing at the switch node LX and damage the device permanently.
- 2. Use wide open areas on the top and bottom layers of the system board as the ground plane (GND) for ft2923. Place lots of solid vias connecting the top and bottom layers of GND. Furthermore, for proper thermal dissipation, reserve wide and uninterrupted GND areas along the thermal flow on the top layer, i.e., no wires cutting through the GND layer and obstructing the thermal flow.
- 3. The ft2923 is packaged with an exposed thermal pad on the underside of the device. Solder the thermal pad directly onto a large grounded metal island, as a thermal sink, underneath the package for proper therma dissipation. On the grounded metal island, place several rows of solid, equally-spaced vias connecting to the bottom layer of GND. Failure to do so can severely limit its thermal dissipation capability. It might even cause the device going into over-temperature shutdown occasionally.
- 4. All the ground pins (AGND, PGND and PGNDB) are directly connected to the ground plane (GND). The power supply inputs (PVDDL/R) for the audio amplifiers' output stages are directly connected to the output capacitors of the boost regulator with wide and short metal traces.
- As a high-performance Class-G stereo audio amplifier, the ft2923 requires adequate power supply decoupling to ensure its high-efficiency, low distortion, and low EMI. Place each decoupling capacitor as individually close to VBAT, AVDD, BVDD, and PVDDL/R pins as possible.
- 6. For best noise performance, use differential inputs from the audio sources for ft2923. In single-ended input applications, the unused inputs of ft2923 should be AC-grounded at the audio source.
- 7. With an on-chip rectification power switch, the ft2923 requires no external Schottky diode for typical applications. However, an auxiliary Schottky diode can be added across the LX and PVOUT pins, as shown in Figure 37, to enhance maximum output power and overall power efficiency. The added Schottky diode must be rated for a current no less than 3A and a reverse breakdown voltage no less than 15V.
- 8. Additional EMI suppression can be achieved using a ferrite bead filter constructed from a ferrite bead and a capacitor, as shown in Figure 30. Choose a ferrite bead with a rated current no less than 1A for an  $8\Omega$  load and 2A for a  $4\Omega$  load. Also, place the ferrite beard filter tightly together and individually close to VOPL/R and VONL/R pins respectively.
- 9. Add a simple RC snubber circuit across two audio outputs (VOPL/R and VONL/R) for each channel, as shown in Figure 31, to prevent the device from accelerated deterioration or abrupt destruction due to excessive inductive flybacks that are induced on fast output switching or by an over-current or short-circuit condition.
- 10. The operation of the battery tracking AGC can be highly influenced by the electrical characteristics of the battery. Place a small decoupling resistor of 10Ω between the battery supply voltage and the VBAT pin, coupled with a decoupling capacitor of 1μF, mitigating the detrimental effect of high battery current ripples on the detection of battery voltage.
- 11. Place a small decoupling resistor of  $10\Omega$  between AVDD and PVOUT pins, coupled with a decoupling capacitor of  $1\mu$ F, preventing high frequency transients from interfering with the on-chip linear amplifiers.
- 12. Use direct low-impedance traces for the audio outputs (VOPL/R and VONL/R) to the output filters and to the speakers.
- 13. Do not connect any audio outputs (VOPL/R or VONL/R) directly to GND, PVOUT, or PVDDL/R as this might damage the device permanently.
- 14. Do not alter the logic state of the SDRIVE pin while the device is in operation. To change the operating mode, the device must be first placed in shutdown mode for a minimum of 100 milliseconds.



#### **FUNCTIONAL BLOCK DIAGRAM**

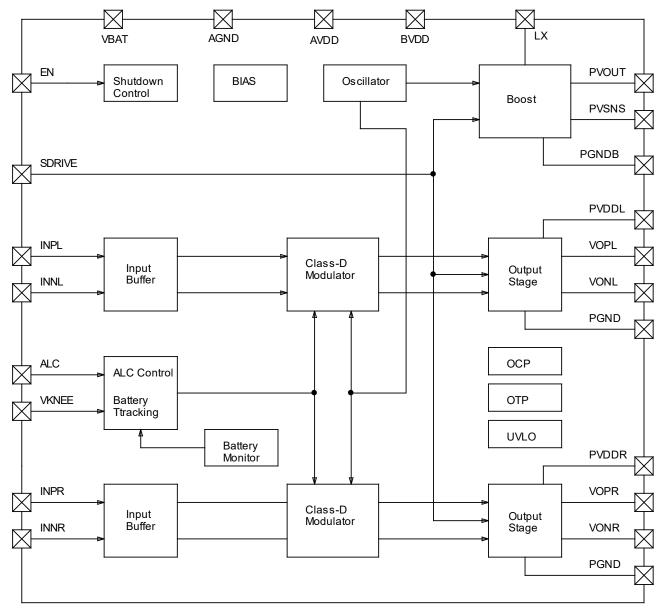


Figure 2: Simplified Functional Block Diagram of ft2923



## ELECTRICAL CHARACTERISTICS (Note 5)

VBAT=3.6V, f=1kHz, Load= $4\Omega+33\mu$ H, L=2.2 $\mu$ H, C $_{IN}$ =0.22 $\mu$ F, R $_{IN}$ =20k $\Omega$  (Av=24dB), ALC=NC, VKNEE=Low, SDRIVE=Low, C $_{S}$ =22 $\mu$ F, C $_{PVOUT}$ =22 $\mu$ F//100 $\mu$ F, C $_{PVDDL/R}$ =1 $\mu$ F, R $_{VBAT}$ =10 $\Omega$ , C $_{VBAT}$ =1 $\mu$ F, R $_{AVDD}$ =10 $\Omega$ , C $_{AVDD}$ =1 $\mu$ F, C $_{BVDD}$ =0.1 $\mu$ F, both channels driven, T $_{A}$ =25°C, unless otherwise specified.

SYMBO	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
VBAT	Supply Input Voltage		3.0		5.5	V
V <sub>UVLOUP</sub>	Power-on Threshold Voltage	VBAT from Low to High		2.2		V
V <sub>UVLODN</sub>	Power-off Threshold Voltage	VBAT from High to Low		2.0		V
I <sub>VBAT</sub>	Supply Quiescent Current	Inputs AC-Grounded, No Load	7	10	14	mA
I <sub>AVDD</sub>	Quiescent Current	V <sub>IN</sub> =0.12V <sub>RMS</sub> , No Load	4	6	9	mA
I <sub>SD</sub>	Shutdown Current	EN Low			1	μA
BVDD	Voltage Reference	Inputs AC-Grounded, No Load	3.0	3.2	3.4	V
	B: 11 11 11 11 11 11 11 11 11 11 11 11 11	EN	1.2			V
$V_{IH}$	Digital High Level Input Voltage	ALC, SDRIVE, VKNEE	VBAT-0.5		VBAT	V
V <sub>IL</sub>	Digital Low Level Input Voltage	EN, ALC, SDRIVE, VKNEE			0.4	V
R <sub>DOWN</sub>	Pulldown Resistor to Ground	EN, ALC, SDRIVE, VKNEE		300		kΩ
R <sub>UP</sub>	Pullup Resistor to VBAT	ALC, SDRIVE, VKNEE		300		kΩ
T <sub>OTSD</sub>	Over-Temperature Threshold			160		°C
T <sub>HYS</sub>	Over-Temperature Hysteresis			20		°C
Class-G	Boost Regulator					
		No Load	6.0	6.2	6.4	V
PVOUT	Boosted Voltage	I <sub>LOAD</sub> =1A		6.0		V
f <sub>BOOST</sub>	PWM Switching Frequency	20.12		800		kHz
		Boost Regulator (SDRIVE=Low	, High Effi	ciency Dr	rive)	1
	Maximum Output Power	$R_L=4\Omega$		4.5		W/Ch
	THD+N=10%	R <sub>L</sub> =8Ω		2.7		W/Ch
P <sub>O, MAX</sub>	Maximum Output Power	$R_L=4\Omega$		3.7		W/Ch
	THD+N=1%	R <sub>L</sub> =8Ω		2.2		W/Ch
		$R_L=4\Omega$ , $V_{IN}=0.40V_{RMS}$		3.5		W/Ch
$P_{O, ALC}$	ALC Output Power	$R_L=8\Omega$ , $V_{IN}=0.40V_{RMS}$		2.0		W/Ch
	Total Harmonic Distortion+Noise	$R_L=4\Omega$ , Po=2W		0.06		%
	(Non-ALC Mode)	R <sub>L</sub> =8Ω, Po=1W		0.06		%
THD+N	Total Harmonic Distortion+Noise	$R_L=4\Omega$ , $V_{IN}=0.40V_{RMS}$		0.3		%
	(ALC Mode)	$R_L=8\Omega$ , $V_{IN}=0.40V_{RMS}$		0.3		%
A <sub>V</sub>	Overall Voltage Gain	R <sub>IN</sub> =20kΩ		24		dB
R <sub>IN</sub>	Input Resistance	@ INPL/R, INNL/R		20		kΩ
V <sub>COMM</sub>	Input Common-Mode Bias	@ INPL/R, INNL/R		1.6		V
R <sub>OUT-SD</sub>	Output Resistance in Shutdown	@ VOPL/R, VONL/R		3		kΩ
V <sub>OS</sub>	Output Offset Voltage	Inputs AC-Grounded		±10		mV
V <sub>N</sub>	Idle-Channel Noise	Inputs AC-Grounded, A-weighted		160		μV <sub>RMS</sub>
SNR	Signal-to-Noise Ratio (Non-ALC Mode)	Maximum Output (Vo=3.8 $V_{RMS}$ ) R <sub>L</sub> =4 $\Omega$ , A-weighted		87		dB
PSRR	Power Supply Rejection Ratio	f=1kHz, Inputs AC-Grounded		70		dB
1 01111		1	1		1	1
CMRR	Common Mode Rejection Ratio	f=1kHz, V <sub>IN</sub> =0.2V <sub>RMS</sub>		60		dB



## **ELECTRICAL CHARACTERISTICS** (Note 5) (Cont'd)

VBAT=3.6V, f=1kHz, Load= $4\Omega+33\mu$ H, L=2.2 $\mu$ H, C<sub>IN</sub>=0.22 $\mu$ F, R<sub>IN</sub>=20k $\Omega$  (Av=24dB), ALC=NC, VKNEE=Low, SDRIVE=Low, C<sub>S</sub>=22 $\mu$ F, C<sub>PVOUT</sub>=22 $\mu$ F//100 $\mu$ F, C<sub>PVDDL/R</sub>=1 $\mu$ F, R<sub>VBAT</sub>=10 $\Omega$ , C<sub>VBAT</sub>=1 $\mu$ F, R<sub>AVDD</sub>=10 $\Omega$ , C<sub>AVDD</sub>=1 $\mu$ F, C<sub>BVDD</sub>=0.1 $\mu$ F, both channels driven, T<sub>A</sub>=25°C, unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
T <sub>STUP</sub>	Startup Time			80		ms
T <sub>SD</sub>	Shutdown Mode Settling Time			40		ms
f <sub>SW</sub>	PWM Output Carrier Frequency			400		kHz
	0 0 11: 3	SDRIVE=Low or High		2.6		A/Ch
I <sub>LIMIT</sub>	Over-Current Limit	SDRIVE=Unconnected		1.6		A/Ch
Automati	c Level Control (ALC)					•
A <sub>MAX</sub>	Maximum ALC Attenuation			13		dB
	ALC Attack Time	ALC-1 Mode (ALC=Low)		6		ms
T <sub>ATTACK</sub>	$(V_{IN}=0.22V_{RMS} \rightarrow 0.70V_{RMS})$	ALC-2 Mode (ALC=Unconnected)		48		ms
+	ALC Release Time	ALC-1 Mode (ALC=Low)		2.0		s
T <sub>RELEASE</sub>	$(V_{IN}=0.70V_{RMS} \rightarrow 0.22V_{RMS})$	ALC-2 Mode (ALC=Unconnected)		1.0		S
Volume F	ade-In & Fade-Out					•
T <sub>FADEIN</sub>	Fade-In Time			20		ms
	Fade-Out Time			20		ms
Battery T	racking AGC	,				1
		VKNEE=High		3.40		V
$V_{KNEE}$	Knee Voltage	VKNEE=Unconnected		3.15		V
S <sub>ATT</sub>	Output Attenuation Slope	@ VOPL/R, VONL/R		3		V/V
	Audio Amplifier with Class-G	Boost Regulator (SDRIVE=High	Soft Driv	/e)		
	Maximum Output Power	$R_L$ =4 $\Omega$		4.5		W/Ch
P <sub>O, MAX</sub>	THD+N=10%	$R_L=8\Omega$		2.7		W/Ch
	Maximum Output Power	$R_L=4\Omega$		3.7		W/Ch
	THD+N=1%	$R_L=8\Omega$		2.2		W/Ch
		$R_L=4\Omega$ , $V_{IN}=0.40V_{RMS}$		3.5		W/Ch
P <sub>O, ALC</sub>	ALC Output Power	$R_L=8\Omega$ , $V_{IN}=0.40V_{RMS}$		2.0		W/Ch
	Total Harmonic Distortion+Noise	R <sub>L</sub> =4Ω, Po=2W		0.07		%
THD+N	(Non-ALC Mode)	R <sub>L</sub> =8Ω, Po=1W		0.07		%
	Total Harmonic Distortion+Noise	$R_L=4\Omega$ , $V_{IN}=0.40V_{RMS}$		0.3		%
	(ALC Mode)	$R_L=8\Omega$ , $V_{IN}=0.40V_{RMS}$		0.3		%
Class-D A	Audio Amplifier w/o Class-G E	Boost Regulator (SDRIVE=Unco	nnected,	Soft Drive	·)	
	Maximum Output Power	$R_L=4\Omega$		1.5		W/Ch
	THD+N=10%	$R_L=8\Omega$		0.90		W/Ch
P <sub>O, MAX</sub>	Maximum Output Power	$R_L=4\Omega$		1.2		W/Ch
	THD+N=1%	R <sub>L</sub> =8Ω		0.70		W/Ch
_		$R_L=4\Omega$ , $V_{IN}=0.20V_{RMS}$		1.1		W/Ch
P <sub>O, ALC</sub>	ALC Output Power	$R_L=8\Omega$ , $V_{IN}=0.20V_{RMS}$		0.65		W/Ch
	Total Harmonic Distortion+Noise	$R_L=4\Omega$ , Po=1W		0.05		%
	(Non-ALC Mode)	R <sub>L</sub> =8Ω, Po=0.5W		0.05		%
THD+N	Total Harmonic Distortion+Noise	$R_L=4\Omega$ , $V_{IN}=0.20V_{RMS}$		2.0		%
	(ALC Mode)	$R_L=8\Omega$ , $V_{IN}=0.20V_{RMS}$		1.0		%



## TYPICAL PERFORMANCE CHARACTERISTICS (Note 5)

VBAT=3.6V, f=1kHz, Load= $4\Omega+33\mu$ H, L=2.2 $\mu$ H, C<sub>IN</sub>=0.22 $\mu$ F, R<sub>IN</sub>=20k $\Omega$  (Av=24dB), ALC=NC, VKNEE=Low, SDRIVE=Low, C<sub>S</sub>=22 $\mu$ F, C<sub>PVOUT</sub>=22 $\mu$ F//100 $\mu$ F, C<sub>PVDDL/R</sub>=1 $\mu$ F, R<sub>VBAT</sub>=10 $\Omega$ , C<sub>VBAT</sub>=1 $\mu$ F, R<sub>AVDD</sub>=10 $\Omega$ , C<sub>AVDD</sub>=1 $\mu$ F, C<sub>BVDD</sub>=0.1 $\mu$ F, both channels driven, T<sub>A</sub>=25°C, unless otherwise specified.

#### **List of Typical Performance Characteristics**

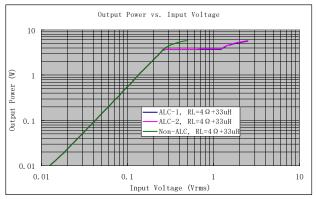
DESCRIPTION	CONDITIONS	FIGURE #
	R <sub>L</sub> =4Ω+33μH, ALC-1 & ALC-2 & Non-ALC Modes	3
Output Dower vo. Input Voltage	$R_L$ =8Ω+33μH, ALC-1 & ALC-2 & Non-ALC Modes	4
Output Power vs. Input Voltage	$R_L$ =4 $\Omega$ +33 $\mu$ H, ALC-1 Mode, SDRIVE=High/Unconnected	5
	$R_L$ =8 $\Omega$ +33 $\mu$ H, ALC-1 Mode, SDRIVE=High/Unconnected	6
Output Dower vo. Supply Voltage	$\label{eq:Vin} V_{\text{IN}}\text{=}0.40V_{\text{RMS}},\ R_{\text{L}}\text{=}4\Omega\text{+}33\mu\text{H},\ VKNEE=\text{High/Unconnected/Low}$	7
Output Power vs. Supply Voltage	$\label{eq:Vin} V_{\text{IN}}\text{=}0.40V_{\text{RMS}},\ R_{\text{L}}\text{=}8\Omega\text{+}33\mu\text{H},\ VKNEE}\text{=}\text{High/Unconnected/Low}$	8
Overell Effective and Control Person	$R_L$ =4 $\Omega$ +33 $\mu$ H, Non-ALC Mode, SDRIVE= Low/High	9
Overall Efficiency vs. Output Power	$R_L$ =8 $\Omega$ +33 $\mu$ H, Non-ALC Mode, SDRIVE=Low/High	10
THD+N vs. Output Power	$R_L$ =4 $\Omega$ +33 $\mu$ H, Non-ALC Mode	11
THD+N vs. Input Voltage	$R_L$ =4 $\Omega$ +33 $\mu$ H, ALC-1 & ALC-2 Modes	12
THD+N vs. Input Frequency	Po=1W/3W, R <sub>L</sub> =4Ω+33μH, ALC-1 & ALC-2 Modes	13
Output Power vs. Input Frequency	$V_{\text{IN}}$ =0.20 $V_{\text{RMS}}$ , $R_{\text{L}}$ =4 $\Omega$ +33 $\mu$ H, Non-ALC Mode, f=20Hz ~ 20kHz	14
PSRR vs. Input Frequency	$R_L$ =4Ω+33μH, Inputs AC-Grounded	15
Quiescent Current vs. Supply Voltage	Input AC-Grounded, R <sub>L</sub> =No Load/4Ω+33μH/8Ω+33μH	16
Startup Output Waveforms	V <sub>IN</sub> =0.1V <sub>RMS</sub>	17
Shutdown Output Waveforms	V <sub>IN</sub> =0.1V <sub>RMS</sub>	18
ALC Release Time	$V_{\text{IN}}$ =0.70 $V_{\text{RMS}}$ $\rightarrow$ 0.22 $V_{\text{RMS}}$ , $R_{\text{L}}$ =4 $\Omega$ +33 $\mu$ H, ALC-1 Mode	19
ALC Release Time	$V_{\text{IN}}$ =0.70 $V_{\text{RMS}}$ $\rightarrow$ 0.22 $V_{\text{RMS}}$ , $R_{\text{L}}$ =4 $\Omega$ +33 $\mu$ H, ALC-2 Mode	20
	$R_L$ =4 $\Omega$ +33 $\mu$ H, $V_{IN}$ =0.2 $V_{RMS}$ , SDRIVE=Low	21
Broadband Output Spectrum	$R_L$ =4 $\Omega$ +33 $\mu$ H, $V_{IN}$ =0.2 $V_{RMS}$ , SDRIVE=High	22
	$R_L\text{=}4\Omega\text{+}33\mu\text{H},V_\text{IN}\text{=}0.2V_\text{RMS},\text{SDRIVE}\text{=}\text{Unconnected}$	23
Mode Transitions of Boost Regulator	$R_L$ =4 $\Omega$ +33 $\mu$ H, Non-ALC Mode	24

Note 5: All parameters are measured according to the conditions specified in Electrical and Typical Performance Characteristics sections with the following notes, unless otherwise specified:

- 5.1 The two differential inputs are shorted for common-mode input voltage measurement. All other parameters are taken with input resistors  $R_{IN}$ =20k $\Omega$  and input capacitors  $C_{IN}$ =0.22 $\mu$ F, unless otherwise specified.
- 5.2 The boost regulator's supply decoupling capacitor C<sub>S</sub>=22μF is placed close to the inductor.
- 5.3 The boost regulator's inductor L=2.2µH and Schottky diode (if present) are placed tightly together and close to the LX pins.
- 5.4 The boost regulator's output capacitors C<sub>PVOUT</sub>=22µF//100µF are placed close to the PVOUT pins.
- 5.5 The audio amplifiers' supply decoupling capacitors C<sub>PVDDL/R</sub>=1µF are placed individually close to PVDDL/R pins.
- 5.6 An output inductor of 33µH is placed in series with the load resistor to emulate a speaker load for all AC and dynamic parameters.
- 5.7 A 33kHz lowpass filter is added even if the analyzer has an internal lowpass filter. An RC lowpass filter (100 $\Omega$ , 47nF) is used on each output for the data sheet graphs.



## **TYPICAL PERFORMANCE CHARACTERISTICS (Cont'd)**



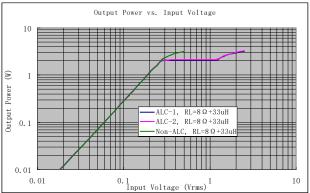
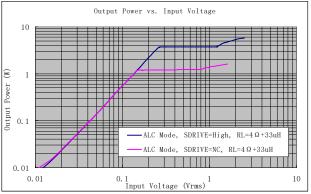


Figure 3: Output Power vs. Input Voltage

Figure 4: Output Power vs. Input Voltage



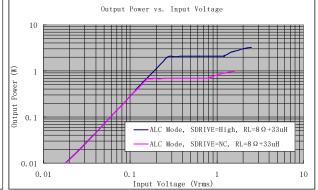
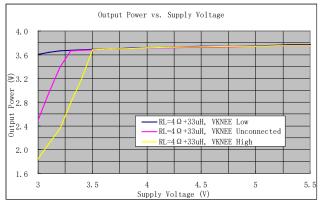


Figure 5: Output Power vs. Input Voltage

Figure 6: Output Power vs. Input Voltage



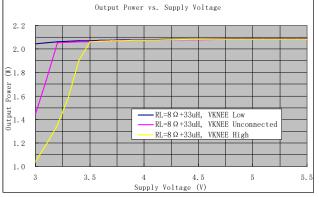


Figure 7: Output Power vs. Supply Voltage

Figure 8: Output Power vs. Supply Voltage



## **TYPICAL PERFORMANCE CHARACTERISTICS (Cont'd)**

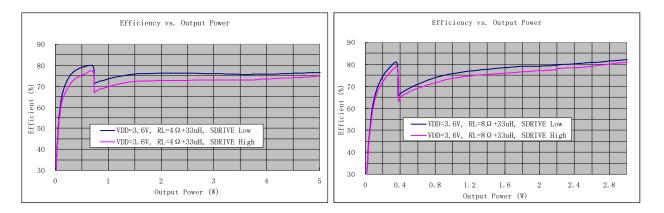


Figure 9: Overall Efficiency vs. Output Power Figure 10: Overall Efficiency vs. Output Power

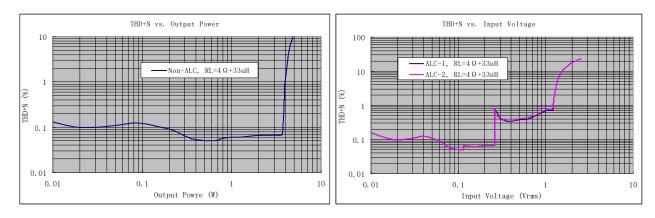


Figure 11: THD+N vs. Output Power

Figure 12: THD+N vs. Input Voltage

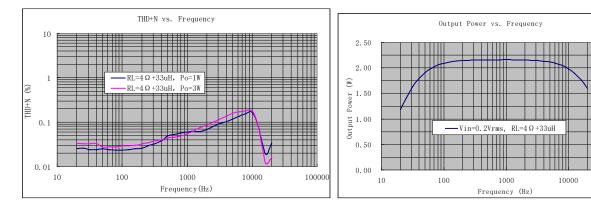


Figure 13: THD+N vs. Input Frequency

Figure 14: Output Power vs. Input Frequency (with 33kHz Lowpass Filter)

100000

5. 5



### **TYPICAL PERFORMANCE CHARACTERISTICS (Cont'd)**

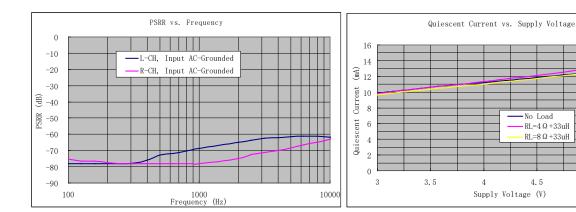


Figure 15: PSRR vs. Input Frequency

Figure 16: Quiescent Current vs. Supply Voltage

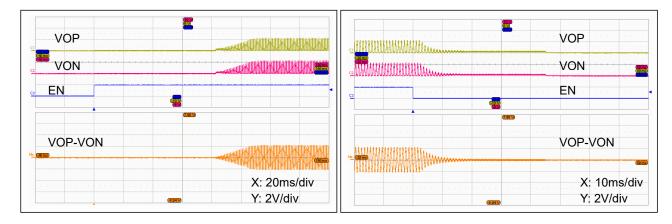


Figure 17: Startup Output Waveforms

Figure 18: Shutdown Output Waveforms

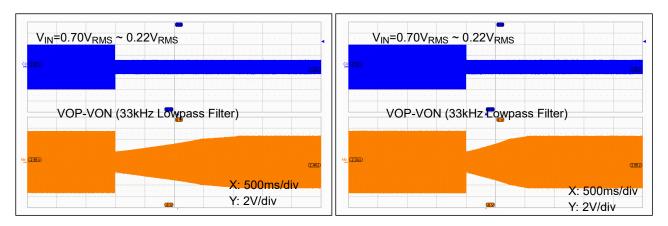


Figure 19: ALC-1 Release Time

Figure 20: ALC-2 Release Time



### **TYPICAL PERFORMANCE CHARACTERISTICS (Cont'd)**

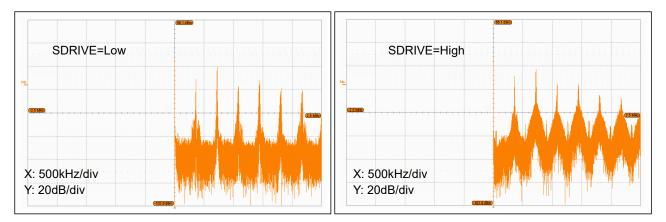


Figure 21: Wideband Output Spectrum

Figure 22: Wideband Output Spectrum

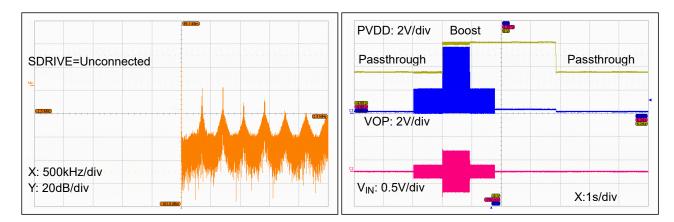


Figure 23: Wideband Output Spectrum

Figure 24: Mode Transitions of Boost Regulator



#### **APPLICATION INFORMATION**

The ft2923 is a highly efficient 2X4.5W Class-G stereo audio power amplifier with automatic level control (ALC) and battery tracking AGC. It integrates dual filterless Class-D audio amplifiers with an adaptive Class-G synchronous boost regulator and operates with a range of supply voltages from 3V to 5.5V. When operating with a 3.6V supply voltage, the ft2923 can deliver an output power of 4.5W per channel with 10% THD+N, or 3.7W per channel with 1% THD+N, into a pair of  $4\Omega$  speakers.

In ft2923, the power supply rails of the audio amplifiers' output stages are internally boosted and regulated by a synchronous PWM switching regulator with two integrated power switches. The boost regulator employs current-mode PWM control with proprietary Class-G operation to regulate the boosted output voltage. The adaptive nature of the Class-G boost regulator, whose output voltage varies dynamically in response to the voltage level of the audio outputs, improves overall power efficiency and extends battery life when playing music. The higher output power and greater power efficiency resulted from the Class-G boost regulator make ft2923 an ideal audio solution for battery-powered electronic devices.

The ft2923 features two modes of operation, i.e., ALC and Non-ALC, which are selected via ALC pin. When the ALC pin is shorted to VBAT, the ft2923 operates in Non-ALC mode, where both audio amplifiers are configured as conventional Class-D amplifiers without ALC. Conversely, when the ALC pin is unconnected or shorted to GND, the ft2923 operates in ALC mode, where it constantly monitors and safeguards the audio outputs against the boosted supply voltage, preventing output clipping distortion, excessive power dissipation, and speaker over-load. Once an over-level condition is detected in either channel, the ALC lowers the voltage gain of both audio amplifiers together to eliminate output clipping while allowing for a maximally-allowed dynamic range of the audio outputs. The ft2923 offers two ALC dynamic characteristics for two distinctive sound effects, which are also selected via the ALC pin. In ALC mode, with a supply voltage at 3.6V, the ft2923 can deliver an ALC output power of 3.5W per channel with 0.3% THD+N, into a pair of  $4\Omega$  speakers.

In conjunction with ALC, as the battery supply voltage drops below a prescribed value, the battery tracking AGC lowers the voltage gain of both audio amplifiers to limit the peak audio outputs, preventing the collapse of battery voltage.

Furthermore, the Class-D audio amplifiers in ft2923 feature filterless PWM modulators that substantially lower or completely eliminate the requirement for external LC filters, reducing the number of external components, the system board space, and the system cost. With filterless PWM modulators, the efficiency of the audio amplifiers is also improved.

As specifically designed for portable applications, the ft2923 incorporates shutdown mode to minimize the power consumption by holding the EN pin to ground. It also includes comprehensive protection features against various operating faults such as over-current, short-circuit, over-temperature, and under-voltage for a safe and reliable operation.

#### ADAPTIVE BOOST REGULATOR

To allow for higher audio loudness, a Class-G boost regulator is integrated in ft2923 to boost the power supply rails (PVDDL/R) of the audio amplifiers' output stages from VBAT to a higher voltage in respond to the voltage level of the audio outputs. For a proper operation, the power supply rails (PVDDL/R) must be externally shorted to PVOUT, the voltage output of the boost regulator, via sufficiently wide metal lines on the system board.

The integrated boost regulator employs fixed-frequency, peak-current PWM scheme with current mode control. The PWM switching frequency is internally set at 800kHz, which allows using smaller inductance and output capacitance for stability and results in a higher PWM control loop bandwidth. Furthermore, the Class-G boost regulator in ft2923 features proprietary adaptive operation. As either one of the audio outputs is higher than the prescribed value for an extended period, the ft2923 enters into Boost mode, where the boost regulator is activated to boost and regulate PVOUT at 6.2V, typically.

Conversely, when both audio outputs are reduced to a value lower than the prescribed value for an extended period, the boost regulator will be de-biased. In this case, the ft2923 is forced into Passthrough mode where both



audio amplifiers' output stages are powered directly from the supply input voltage, through the external inductor and the on-chip rectification power switch. Note that in Passthrough mode, PVOUT is equal to the supply input voltage minus the voltage drop across the rectification power switch.

The adaptive nature of the Class-G boost regulator in ft2923, where PVOUT varies dynamically in response to the voltage level of the audio outputs, can greatly improve overall power efficiency and extend battery life when playing music. The higher output power and greater efficiency make the ft2923 an ideal audio solution for battery-powered electronic devices.

#### DESIGN GUIDELINES OF BOOST REGULATOR

#### **Selection of Boost Regulator Inductor**

The selection of the inductor is the most important parameter in the design of power switching regulators since it affects boost regulator's steady-state operation as well as dynamic response and loop stability. Three important inductor specifications are to be considered: Inductor value, DC resistance (DCR), and Saturation current. Note that inductor values may have tolerance up to  $\pm 20\%$  with zero-current bias. Also, when the inductor current approaches its saturation limit, the effective inductance can fall to a fraction of its zero-current value. For most applications of ft2923, it is recommended that the peak (saturation) current rating of the inductor is no less than 6A.

In general, a larger inductance value produces less inductor current ripple, which in turn results in lower inductor peak current, higher possible output current, lower EMI, and higher efficiency. On the other hand, a smaller inductance value, with a physically small size, results in improved transient response with higher inductor peak current and potentially worse EMI and lower efficiency. An inductor of  $1.5\mu H \sim 3.3\mu H$  suffices for most applications of ft2923. Do not use any inductance higher than  $4.7\mu H$  as it might slow the boost regulator's response to output load transients with little incremental improvements on the output current capability and efficiency. Select an inductor with DCR less than  $50m\Omega$  for higher overall efficiency (from the power supply to the speaker load).

#### **Selection of Boost Regulator Output Capacitor**

The output capacitor of the boost regulator is required to keep the output voltage ripple small and ensure the stability of the PWM control loop. The output capacitor must have low equivalent-series-resistance (ESR) at the PWM switching frequency, so ceramic capacitors are the best choice. Make sure that the output capacitor maintains its capacitance over the specified range of DC bias and operating temperature. A  $22\mu F$  low-ESR ceramic capacitor suffices for most applications with speaker load impedances of  $8\Omega$ . For applications where the speaker load impedances are  $4\Omega$  or less, use a pair of  $22\mu F$  low-ESR ceramic capacitors.

A bulk output capacitor (either electrolytic or tantalum) is typically added to facilitate higher voltage margin for higher audio power at low frequencies. However, be cautious using any bulk output capacitance higher than 100µF as it might adversely slow the boost regulator's response to load transients to some extent affecting audio dynamics when playing music.

Also, add a small, good quality, low-ESR ceramic capacitor of 0.1µF in close proximity to the PVOUT pins for high-frequency filtering.

The boost regulator's output, PVOUT, must be externally connected to the power supply rails of the audio amplifiers' output stages, PVDDL/R, on the system board with wide and short metal traces.

#### **Selection of Boost Regulator Schottky Diode (Optional)**

A rectification power switch is integrated in the synchronous boost regulator of ft2923, thus no external Schottky diode is required for typical applications. However, an auxiliary Schottky diode can be added across LX and PVOUT pins to enhance maximum output power and overall power efficiency. The added Schottky diode must be rated for a current more than 3A and a reverse breakdown voltage more than 15V.



#### Selection of Boost Regulator Input Capacitor

In practice, supply input capacitors are required for boost regulators. The supply input capacitor acts as a charge reservoir for the inductor current, providing energy faster than the system power supply, mitigating current surges or voltage droops of the supply voltage.

At least  $10\mu\text{F}$  of input capacitance is required for supply decoupling for ft2923. The rated voltage of the input capacitor must be higher than the supply input voltage with sufficient tolerance to limit the effects of dc bias. For most applications where the power supply is reasonably designed, a low-ESR ceramic capacitor of  $22\mu\text{F}$ , 16V with  $10\text{m}\Omega$  ESR is sufficient for ft2923. Also, add a small, good quality, low-ESR ceramic capacitor of  $0.1\mu\text{F}$  in close proximity to the inductor for high-frequency supply decoupling.

For applications where additional input capacitance is required to meet the requirement of the input current ripple or transient response, place an electrolytic or tantalum bulk capacitor between  $47\mu F$  and  $100\mu F$  in close proximity to ft2923. The bulk capacitor acts as a charge reservoir for the inductor current, providing energy faster than the system power supply, mitigating current surges and/or voltage droops of the supply voltage.

#### **AUTOMATIC LEVEL CONTROL (ALC)**

The automatic level control (ALC) is to maintain the audio outputs for a maximum voltage swing without clipping when excessive inputs that may cause clipping distortion are applied. With ALC, the ft2923 lowers the gain of the audio amplifiers to an appropriate value such that output clipping is substantially eliminated.

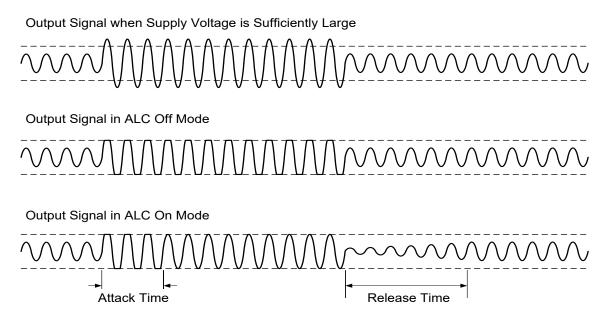


Figure 25: Automatic Level Control Diagram

The attack time and release time of the ALC are shown in Table 1. The attack time is defined as the time interval required for the gain to fall to its steady-state gain less 3dB approximately, assumed that a sufficiently large input signal is applied. The release time is the time interval required for the amplifier to exit out of the present mode of operation.

ALC	Mode of Operation Attack Time (ms)		Release Time (s)
Low	ALC-1	6	2.0
Unconnected	ALC-2	48	1.0
High	Non-ALC	N/A	

Table 1: Attack Time & Release Time



#### ALC MODE CONTROL

The ft2923 can be configured in ALC or Non-ALC mode via the ALC pin, as described in Table 1. When the ALC pin is shorted to VBAT, the ft2923 operates in Non-ALC mode. The Non-ALC operation is typically chosen for applications where maximum audio loudness is much desired and output clipping distortion can be properly controlled and largely eliminated at the audio sources. Conversely, when the ALC pin is left unconnected or shorted to GND, the ft2923 operates in ALC mode with two sets of dynamic characteristics. For most applications, the ALC mode of operation is much preferred for its capability to substantially eliminate output clipping distortion, excessive power dissipation, and speaker over-load.

Two sets of ALC dynamic characteristics can be selected for specific sound effects, as described in Table 1. The ALC-1 mode, where the ALC pin is shorted to GND, tends to play music in a mellower manner with negligible amount of clipping distortion and lower average output power (loudness). On the other hand, the ALC-2 mode, where the ALC pin is left unconnected, tends to play music in a more dynamic manner with higher average output power and some extent of clipping distortion.

#### **VOLTAGE GAIN SETTING**

The voltage gain of the audio amplifier can be externally adjusted by inserting additional input resistors in series with input capacitors, as depicted in Figure 26 and 27. In typical applications, it is required that  $C_{IN} = C_{INL1} = C_{INR1} = C_{INR2}$  and  $C_{IN} = C_{INL1} = C_{INR2} = C_{INR2}$  and  $C_{IN} = C_{INR1} = C_{INR2} = C_{INR2}$  and  $C_{IN} = C_{INR2} = C_{INR3} = C_{INR3$ 



Figure 26: Gain Setting (Differential Inputs) Figure 27: Gain Setting (Single-Ended Inputs)

The value of  $R_{IN}$  (in  $k\Omega$ ) for a given voltage gain can be calculated by Equation 1. Table 2 shows suitable resistor values of  $R_{IN}$  that can be used for various voltage gains, where  $A_V$  is the voltage gain of the audio amplifier.

$$A_{V} = \frac{600}{R_{IN} + 20}$$
 (1)

R <sub>IN</sub> (kΩ)	0	3.9	6.8	10	14	18	22	27	33	39	47	56
A <sub>V</sub> (V/V)	30	25	22.4	20	17.6	15.8	14.3	12.8	11.3	10	9	8
A <sub>V</sub> (dB)	29.5	28	27	26	25	24	23	22	21	20	19	18

**Table 2: External Input Resistors Required for Various Voltage Gains** 

The choice of the voltage gain will strongly influence the loudness and quality of audio sounds. In general, the higher the voltage gain is, the louder the sound is perceived. However an excessive voltage gain may cause the audio outputs to be noticeably compressed or clipped for high-level (loud) audio sounds. On the other hand, an unusually low gain may cause relatively low-level (quiet) sounds soft or inaudible. Thus it is crucial to choose a proper voltage gain for well balanced audio quality.

The voltage gain is chosen based upon various system-level considerations including the boosted supply voltage, dynamic range of the audio source, output power rating, and desired sound effect. The voltage gain can be simply expressed in Equation 2. In the equation,  $V_{IN,\;MAX}$  (in  $V_{RMS}$ ) is the maximum input level from the audio source, PVDD (in volts) is the boosted supply voltage, and  $\alpha$  is a design parameter at user's discretion, which ranges from 0.65 to 2.2. The ALC dynamic range (maximum attention) is linearly proportional to  $\alpha$ . Higher  $\alpha$ 



results in higher ALC dynamic range (maximum attenuation) and higher average output power (loudness) with some degree of compression for high-level audio sounds.

$$A_{V} = \frac{\alpha \times PVDD}{V_{IN, MAX}}$$
 (2)

As an example, Table 3 shows the voltage gain for various audio input levels with  $\alpha$  at about 1.25. In the table,  $R_{IN}$  is the external input resistor in series with the input capacitor.

VIN, MAX (VRMS)	R <sub>IN</sub> (kΩ)	A <sub>V</sub> (V/V)	A <sub>V</sub> (dB)
0.30	6.8	22.4	27
0.50	18	15.8	24
0.70	33	11.3	21
1.0	56	8	18

**Table 3: Typical Voltage Gain Settings for Various Audio Input Levels** 

#### **SOFT DRIVE MODE**

To facilitate low-EMI operation to minimize FM interference, the ft2923 features proprietary edge-rate-control gate drivers for both Class-D audio amplifiers and the Class-G boost regulator. In the soft drive mode, the EMI emissions will be largely reduced at the expense of lower power efficiency, however, much higher than the traditional Class-AB audio amplifiers. Furthermore, to further reduce EMI emissions, the boost regulator can be disabled at the expense of much lower maximum output power due to the limited power supply (the battery voltage) available to the audio amplifiers. Three operating modes are available in ft2923 and can be selected via the SDRIVE pin, as described in Table 4.

SDRIVE	Boost Regulator	Driver Mode	Description
Low	Enable	High Efficiency Drive	High Efficiency, High Power Operation
Unconnected	Disable	Soft Drive	Lowest EMI, Low Power Operation
High	Enable	Soft Drive	Low EMI, Medium Power Operation

**Table 4: Soft Drive Mode Control** 

#### **BATTERY TRACKING AGC**

The ft2923 features battery tracking AGC to limit the peak audio outputs as the battery voltage droops. Although it will affect audio output loudness on low battery voltages, the battery tracking AGC limits high battery current at the end-of-charge battery voltage and prevents the battery voltage from collapsing, which might cause a reset of the system. The battery tracking AGC keeps the peak audio outputs below a limiting value that is a function of the battery supply voltage. The peak output voltage is maintained at PVDD for battery voltages down to the knee voltage and reduced linearly at a rate of 4V/V for lower battery voltages. The knee voltage of the battery tracking AGC can be selected via the VKNEE pin, as described in Table 5. Note that the battery tracking AGC can be enabled only when the ALC function is enabled where the ALC pin is left unconnected or shorted to GND.

VKNEE	Knee Voltage (V)		
Low	Battery Tracking AGC Disabled		
Unconnected	3.15		
High	3.40		

**Table 5: Battery Tracking AGC Control** 



The operation of the battery tracking AGC can be highly influenced by the electrical characteristics of the battery used with ft2923. Place a small decoupling resistor of  $10\Omega$  between the battery supply voltage and the VBAT pin in conjunction with a decoupling capacitor of  $1\mu F$ , mitigating the detrimental effect of high battery current ripples on the detection of battery voltage.

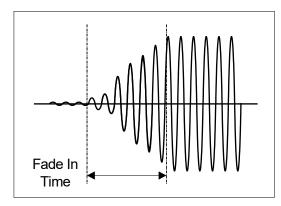
#### SHUTDOWN AND STARTUP

The ft2923 employs the EN pin to minimize power consumption while it is not in use. When the EN pin is pulled to ground, the ft2923 is forced into shutdown mode, where all the analog circuitry is de-biased and the supply current is reduced to be less than  $1\mu$ A, and the differential outputs are shorted to ground through an internal resistor  $(3k\Omega)$  individually. Once in shutdown mode, the EN pin must remains low for at least 40ms  $(T_{SD})$ , the shutdown settling time, before it can be brought high again. When the EN pin is asserted high, the device exits out of shutdown mode and enters into normal operation after the startup time  $(T_{STUP})$  of 80ms.

Note that an internal pulldown resistor of  $300k\Omega$  is included onto the EN pin. Thus, shutdown mode is the state when the power supply is first applied to the device. Whenever possible, it is recommended to assert EN high to exit the device out of shutdown mode only after the device is properly started up. Also, place the amplifier in shutdown mode prior to removing the power supply voltage for the best power-off pop performance.

#### **VOLUME FADE-IN & FADE-OUT**

The volume fade-in/out function is activated whenever the EN state is toggled. It can reduce intermittent sound considerably and eliminate uncomfortable hearing experience.



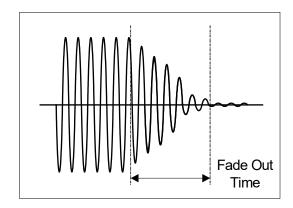


Figure 28: Fade-In Output Waveform

Figure 29: Fade-Out Output Waveform

#### **CLICK-AND-POP SUPPRESSION**

The ft2923 features comprehensive click-and-pop suppression. During startup, the click-and-pop suppression circuitry reduces any audible transients internal to the device. When entering into shutdown, the differential audio outputs ramp down to ground quickly and simultaneously.

#### PSRR ENHANCEMENT

Without a dedicated pin for the common-mode voltage bias, the ft2923 achieves a PSRR, 70dB at 1kHz.

#### PROTECTION MODES

Against various operating faults for a safe and reliable operation, the ft2923 features comprehensive protection modes including Under-Voltage Lockout (UVLO), Over-Current Protection (OCP), and Over-Temperature Shutdown (OTSD).

#### **Under-Voltage Lockout (UVLO)**

The ft2923 incorporates a circuitry to detect a low supply voltage. When the supply voltage is first applied, the ft2923 will remain inactive until the supply voltage exceeds 2.2V ( $V_{UVLU}$ ). When the supply voltage is removed and drops below 2.0V ( $V_{UVLD}$ ), the ft2923 enters into shutdown mode immediately.

#### Over-Temperature Shutdown (OTSD)

When the die temperature exceeds a preset threshold (160°C), the device enters into over-temperature



shutdown mode, where two differential outputs are pulled to ground through an internal resistor  $(3k\Omega)$  individually. The device will resume normal operation once the die temperature returns to a lower temperature, which is about  $20^{\circ}$ C lower than the threshold.

#### **Over-Current Protection (OCP)**

During operation, the output of Class-D amplifier constantly monitors for any over-current or short-circuit conditions. When an over-current condition between two differential outputs, differential output to PVDDL/R or PGND is detected, the output stage of the amplifier is immediately forced into high impedance state. Once the fault condition persists over a prescribed period, the ft2923 then enters into shutdown mode and remains in this mode for about 8ms. When shutdown mode times out, the ft2923 will initiate another startup sequence and then check if the over-current condition has been removed. If the fault condition is still present, the ft2923 will repeat itself for the process of a startup followed by detection, qualification, and shutdown. It is the so-called hiccup mode of operation. Once the fault condition is removed, the ft2923 automatically resumes normal operation.

Although the output stages of the Class-D audio amplifiers can withstand a short between VOPL/R and VONL/R, do not connect any audio outputs directly to GND, PVOUT, or PVDDL/R as this might damage the device permanently.

#### **CLASS-D AUDIO AMPLIFIER**

The Class-D audio amplifiers in the ft2923 operate in much the same way as traditional Class-D amplifiers and similarly offer much higher power efficiency than Class-AB amplifiers. The high efficiency of Class-D operation is achieved by the switching operation of the output stage of the amplifier. The power loss associated with the output stage is limited to the conduction and switching loss of the power switches, which are much less than the power loss associated with a linear output stage in Class-AB amplifiers.

#### **Fully Differential Amplifier**

The ft2923 includes a pair of fully differential amplifiers with differential inputs and outputs. The fully differential amplifiers ensure that the differential output voltages are equal to the differential input voltages times the amplifier gain. Although the ft2923 supports for a single-ended input, differential inputs are much preferred for applications where the environment can be noisy in order to ensure maximum SNR.

#### **Low-EMI Filterless Output Stage**

Traditional Class-D amplifiers require for the use of external LC filters, or shielding, to meet EN55022B electromagnetic-interference (EMI) regulation standards. The ft2923 applies an edge-rate control circuitry to reduce EMI emissions, while maintaining high power efficiency.

#### Filterless Design

Traditional Class D amplifiers require an output filter to recover the audio signal from the amplifier's output. The filter adds cost, increases the solution size of the amplifier, and can adversely affect efficiency and THD performance. The traditional PWM scheme uses large differential output swings (twice of the supply voltage) and causes large ripple currents. Any parasitic resistance in the filter components results in loss of power and lowers the efficiency.

The ft2923 does not require an output filter. The device relies on the inherent inductance of the speaker coil and the natural filtering of both the speaker and the human ear to recover the audio component of the square-wave output. By eliminating the output filter, a smaller, less costly, and more efficient solution can be accomplished.

Because the frequency of the audio outputs from ft2923 output is well beyond the bandwidth of most speakers, voice coil movement due to the square-wave frequency is very small. Although this movement is small, a speaker not designed to handle the additional power can be damaged. For optimum performance, use speakers with series inductances greater than 10uH. Typical  $4\Omega$  speakers exhibit series inductances in the range from  $10\mu\text{H}$  to  $47\mu\text{H}$ .



#### **EMI Reduction**

The ft2923 does not require an LC output filter for the connections from amplifier outputs to speakers. However, additional EMI suppressions can be made by use of a ferrite bead filter comprising a ferrite bead and a capacitor, as shown in Figure 30. Choose a ferrite bead with low DC resistance (DCR) and high impedance  $(100\Omega \sim 330\Omega)$  at high frequencies (>100MHz). The current flowing through the ferrite bead must be also taken into consideration. The effectiveness of ferrites can be greatly aggravated at much lower than the rated current values. Choose a ferrite bead with a rated current value no less than 2A. The choice of the capacitor (less than 1nF) is based upon the ferrite bead, the actual speaker lead length, and the required EMI performance. Place each ferrite bead filter tightly together and individually close to VOPL/R and VONL/R pins respectively.

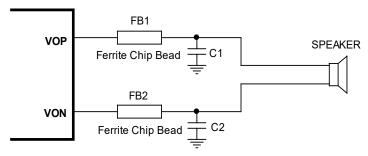


Figure 30: Ferrite Bead Filter to Reduce EMI

#### **Class-D Output Snubber Circuit**

For applications where speaker load resistances are  $4\Omega$  or less, it may become necessary to add a snubber circuit across the two output pins, VOPL/R and VONL/R, to prevent the device from accelerated deterioration or abrupt destruction due to excessive inductive flybacks that are induced on fast output switching or by an over-current or short-circuit condition. The snubber circuit can further lower EMI emission of Class-D outputs.

Figure 31 shows a simple RC snubber circuit with suggested values of  $R=4.7\Omega$  in series with C=4.7nF. Note that the design of the RC snubber circuit is specific to each application and must take into account the parasitic reactance of the system board to reach proper values of R and C. Evaluate and ensure that the voltage spikes (overshoots and undershoots) at VOPL/R and VONL/R on the actual system board are within their absolute maximum ratings. Pay close attention to the layout of the RC snubber circuit to be tight and individually close to VOPL/R and VONL/R pins respectively.

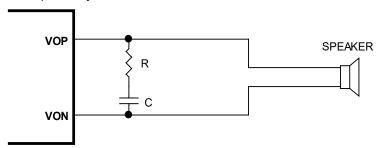


Figure 31: RC Snubber Circuit for Class-D Audio Outputs

#### Input Capacitors (CIN)

DC decoupling capacitors for audio inputs (INPL/R and INNL/R) are recommended. The input audio DC decoupling capacitors will remove the DC bias from audio inputs. The input capacitor  $C_{IN}$  and the total input resistance ( $R_{IN}$  + 20k $\Omega$ ) form a highpass filter with the corner frequency,  $f_C$ , determined by Equation 3.

$$f_C=1 \ / \ [2 \ x \ \pi \ x \ (R_{IN} + 20 k\Omega) \ x \ C_{IN}] \eqno(3)$$
 where  $R_{IN}=R_{INL1}=R_{INL2}=R_{INR1}=R_{INR2}$  and  $C_{IN}=C_{INL1}=C_{INL2}=C_{INR1}=C_{INR2}$ 

In Equation 3,  $R_{IN}$  is the external input resistance for a specific voltage gain. Note that the variation of the actual input resistance will affect the voltage gain proportionally. Thus choose  $R_{IN}$  with a tolerance of 2% or better.



Choose  $C_{IN}$  such that fc is well below the lowest frequency of interest. Setting it too high affects the amplifiers' low-frequency response. Consider an example where the specification calls for  $A_V$ =24dB and a flat frequency response down to 20Hz. In this example,  $R_{IN}$ =20k $\Omega$  and  $C_{IN}$  is calculated to be about 0.20 $\mu$ F; thus 0.22 $\mu$ F, as a common choice of capacitance, can be chosen for  $C_{IN}$ .

Note that any mismatch in the resistance and capacitance between two audio inputs will cause a mismatch in the corner frequencies. Severe mismatch may also cause turn-on pop noise, PSRR, CMRR performance. Choose input resistors and capacitors with a tolerance of ±2% or better.

Furthermore, the type of the input capacitor is crucial to audio quality. For best audio quality, use capacitors whose dielectrics have low voltage coefficients, such as tantalum or aluminum electrolytic. Capacitors with high-voltage coefficients, such as ceramics, may result in increased distortion at low frequencies.

#### Supply Decoupling Capacitors (C<sub>VBAT</sub>, C<sub>PVDDL/R</sub>, C<sub>AVDD</sub>, C<sub>BVDD</sub>)

Sufficient decoupling of the power supplies is crucial for audio amplifiers to ensure high efficiency, low distortion, and low EMI. Place a  $1\mu F$  low-ESR ceramic capacitor ( $C_{VBAT}$ ) in close proximity to the VBAT pin. Furthermore, add a small decoupling resistor ( $R_{VBAT}$ ) of  $10\Omega$  between the system power supply and the VBAT pin, minimizing the detrimental effect of high battery current ripples on the detection of battery voltage.

Place a 1µF low-ESR ceramic capacitor (CPVDDL/R) individually close to each PVDDL/R pin.

Place a 1 $\mu$ F low-ESR ceramic capacitor C<sub>AVDD</sub> close to the AVDD pin. This capacitor type and placement of C<sub>AVDD</sub> help minimize higher frequency transients, spikes, or digital hash on the supply line. Furthermore, add a small decoupling resistor (R<sub>AVDD</sub>) of 10 $\Omega$  between AVDD and PVOUT pins, preventing high frequency transients of PVOUT from interfering with on-chip linear amplifiers.

Place a 0.1µF low-ESR ceramic capacitor C<sub>BVDD</sub> close to the BVDD pin for high-frequency filtering.

#### PRINTED CIRCUIT BOARD (PCB) LAYOUT GUIDELINES

Ground Plane - It is required to use a solid metal plane with sufficiently wide area as a central ground connection (GND) for ft2923. All ground pins (AGND, PGND, and PGNDB) are directly shorted to the ground plane.

Supply Decoupling capacitors – The supply decoupling capacitors ( $C_{VBAT}$ ,  $C_{PVDDL/R}$ ,  $C_{AVDD}$ , and  $C_{BVDD}$ ) should be placed as individually close to VBAT, PVDDL/R, AVDD, and BVDD pins as possible.

Boost Regulator Input Capacitors - Place the supply input capacitors (C<sub>S</sub>) in close proximity to the inductor. They should be on the same layer of the system board with ft2923.

Boost Regulator Inductor & Schottky Diode - Place the inductor and Schottky diode tightly together and in close proximity to the LX pins. They should be on the same layer of the system board with ft2923.

Boost Regulator Snubber Circuit - Place the snubber circuit ( $R_{LX}$  and  $C_{LX}$ ) tightly together and in close proximity to the LX pins. They should be on the same layer of the system board with ft2923.

Boost Regulator Output Capacitors - Place the output capacitors (CPVOUT) in close proximity to the PVOUT pins.

Ferrite Bead Filter - The ferrite bead filters of the Class-D amplifiers' outputs should be placed as individually close to audio output pins, VOPL/R and VONL/R, as possible for optimum EMI performance. Keep the current loop from each of the audio outputs through the ferrite bead and the capacitor and back to PGND as short and tight as possible.

Power Dissipation - The maximum output power of ft2923 can be severely limited by its thermal dissipation capability. To ensure the device operates properly and reliably at maximum output power without incurring over-temperature shutdown, the following guidelines are given for optimization of its thermal dissipation capability:

- Fill both top and bottom layers of the system board with solid GND metal traces.
- Solder the thermal pad directly onto a grounded metal plane.



- Place lots of equally-spaced vias underneath the thermal pad connecting the top and bottom layers of GND. The vias are connected to a solid metal plane on the bottom layer of the board.
- Reserve wide and uninterrupted areas along the thermal flow on the top layer, i.e., no wires cutting through the GND layer and obstructing the thermal flow.
- Place all the passive devices (Inductor, Schottky diode, and Input/output capacitors) of the boost regulator tightly together and on the same layer of the board with ft2923.
- Avoid using vias for traces carrying high current.



#### **PCB LAYOUT EXAMPLE**

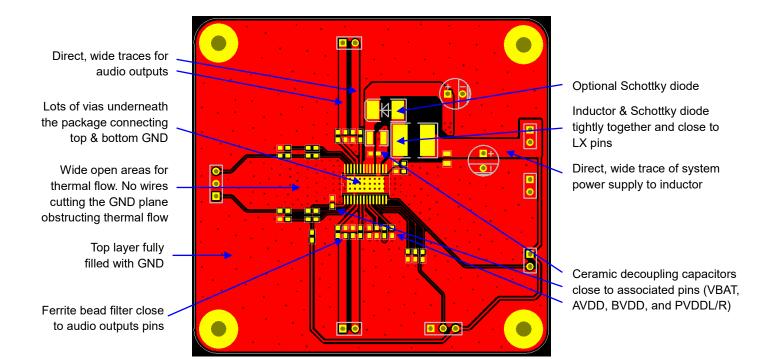


Figure 32: Top Layer of Layout Example

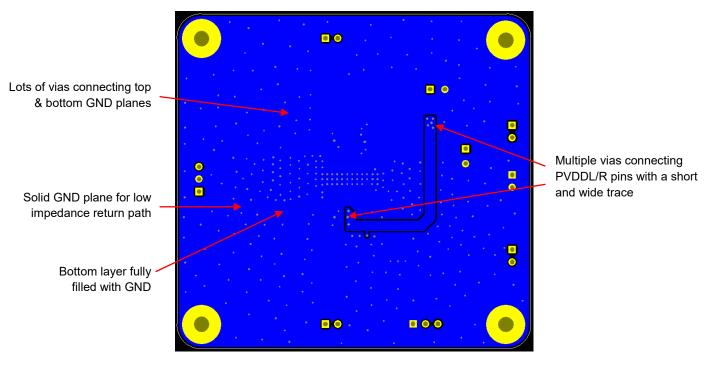


Figure 33: Bottom Layer of Layout Example



#### TYPICAL APPLICATION CIRCUITS

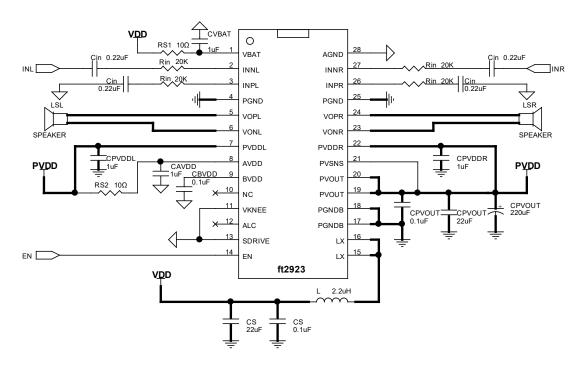


Figure 34: Single-Ended Inputs with High Efficiency Drive in ALC-2 Mode

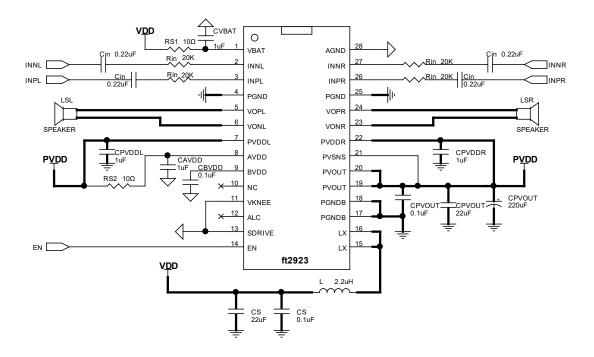


Figure 35: Differential Inputs with High Efficiency Drive in ALC-2 Mode

Note: The bold lines indicate high current paths and their respective traces are required to be as wide and short as possible on the system board for optimum performance in maximum output power, power efficiency, THD+N, and EMI emissions.



## **TYPICAL APPLICATION CIRCUITS (Cont'd)**

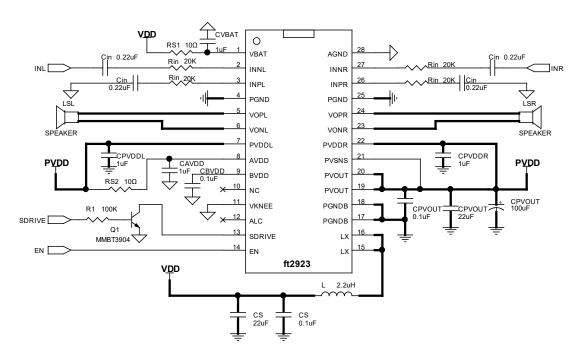


Figure 36: Single-Ended Inputs with Soft Drive Control in ALC-2 Mode

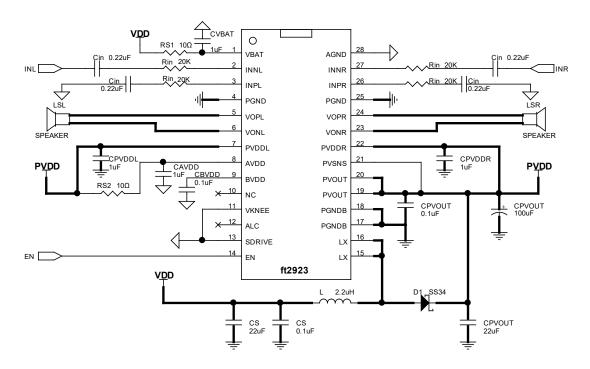


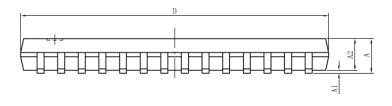
Figure 37: Single-Ended Inputs with an Auxiliary Schottky Diode in ALC-2 Mode

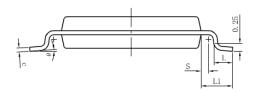
Note: The bold lines indicate high current paths and their respective traces are required to be as wide and short as possible on the system board for optimum performance in maximum output power, power efficiency, THD+N, and EMI emissions.

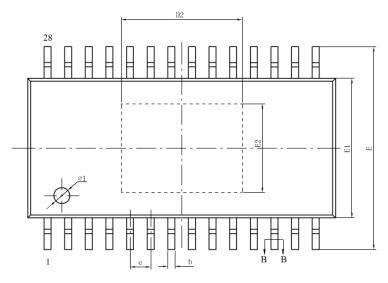


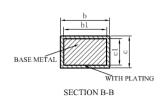
### **PHYSICAL DIMENSIONS**

#### **TSSOP-28L PACKAGE OUTLINE DIMENSIONS**









SYMBOL	MILLIMETER		
STMBOL	MIN	NOM	MAX
A			1.20
A1	0.05		0.15
A2	0.80		1.00
b	0.19		0.30
b1	0.19	0.22	0.25
С	0.09		0.20
c1	0.09		0.16
D	9.60	9.70	9.80
D2	3.71	3.81	3.91

SYMBOL	MILLIMETER			
	MIN	NOM	MAX	
Е	6.25	6.40	6.55	
E1	4.30	4.40	4.50	
E2	2.69	2.79	2.89	
e	0.65BSC			
L	0.50	0.60	0.70	
L1	1.00BSC			
S	0.20			
Ø1	Ø1.0X0. 05~0. 10DP			
θ	1	_	7°	



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